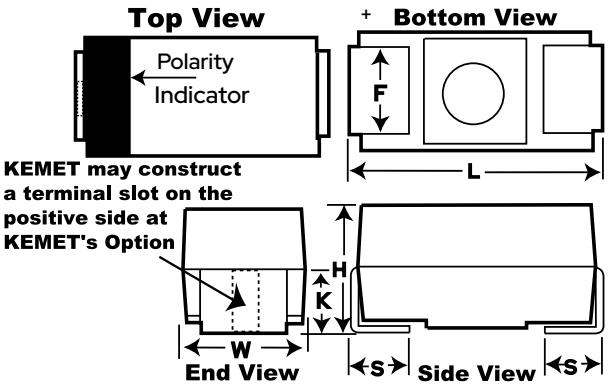
T495B106K010ZTE6007280

Obsolete

B450, Tantalum, MnO2 Tantalum, 10 uF, 10%, 10 VDC, SMD, Molded, Low ESR, Surge Robust, 600 mOhms, 3528, 2.1 mm, 0.7 mm



General Information	
Series	B450
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, Molded, Low ESR, Surge Robust
Features	Low ESR, Surge Robust
RoHS	Yes
Termination	Tin
AEC-Q200	No

Dimensions	
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
H	1.9mm +/-0.2mm
S	0.7mm +/-0.3mm
F	2.2mm +/-0.1mm

Packaging Specifications	
Packaging	T&R, 330mm
Packaging Quantity	8000

Specifications	
Capacitance	10 uF
Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
ESR	0.6 Ohms (100kHz)
Ripple Current	380 mAmps (25C), 342 mAmps (85C), 152 mAmps (125C)
Leakage Current	1 uA